

# 802.3ds 200Gbps/lane 1060nm Proposal from 802.3df to beyond 802.3ds

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Lightera  
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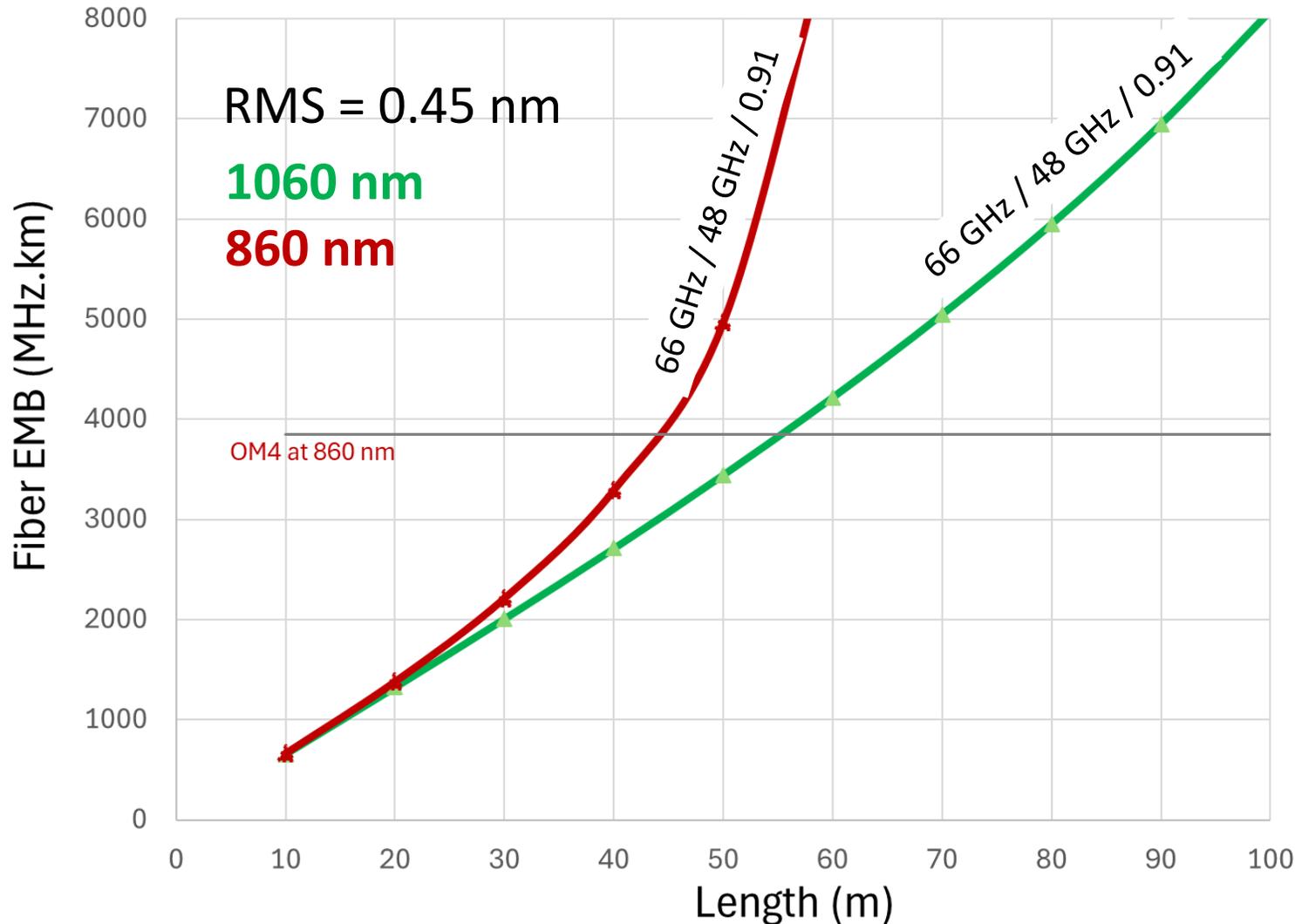
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# IEEE P802.3 ds Baseline Proposal on 1060 nm Transmitter and Fiber Types

PMD Type	200 GBASE-xxR1			Unit
	400 GBASE-xxR2			
	800 GBASE-xxR4			
	1.6 TBASE-xxR8			
Signaling rate, each lane	106.25 ± 50 ppm			GBd
Modulation format	PAM4			
Center wavelength	1060 (TBD)			nm
RMS spectral width	0.45 (TBD)			nm
Encircled flux	≥ 86% at 19 μm    TBD ≤ 30% at 4.5 μm    TBD			
Fiber Type	OML3	OML4	OML5 ?	
Nominal core diameter	TBD			μm
Operating distance	0.5 to 30	0.5 to 50	0.5 to TBD	m
Effective modal bandwidth	≥ 2010 TBD	≥ 3420 TBD	TBD	MHz.km
Zero dispersion wavelength ( $\lambda_0$ )	1297 ≤ $\lambda_0$ ≤ 1328    TBD			nm
Chromatic dispersion slope (max) ( $S_0$ )	-142/(840(1 - ( $\lambda_0/840$ ) <sup>4</sup> ))    TBD			ps/nm <sup>2</sup> km
All other TxRx and fiber parameters	same as .3df or TBD			

- 1060nm fiber EMB is based on
- Fiber 3dBo BW as 66GHz
  - Fiber 3dBe BW as 48GHz
  - Fiber 3dBe BW / Nyquist Freq = 0.91

# Fiber EMB vs Reach @ 212Gbps/lane



At the same reach

- 1060 nm needs less EMB

At the same EMB

- 1060 nm can reach longer

Benefits of 1060 nm is more obvious at

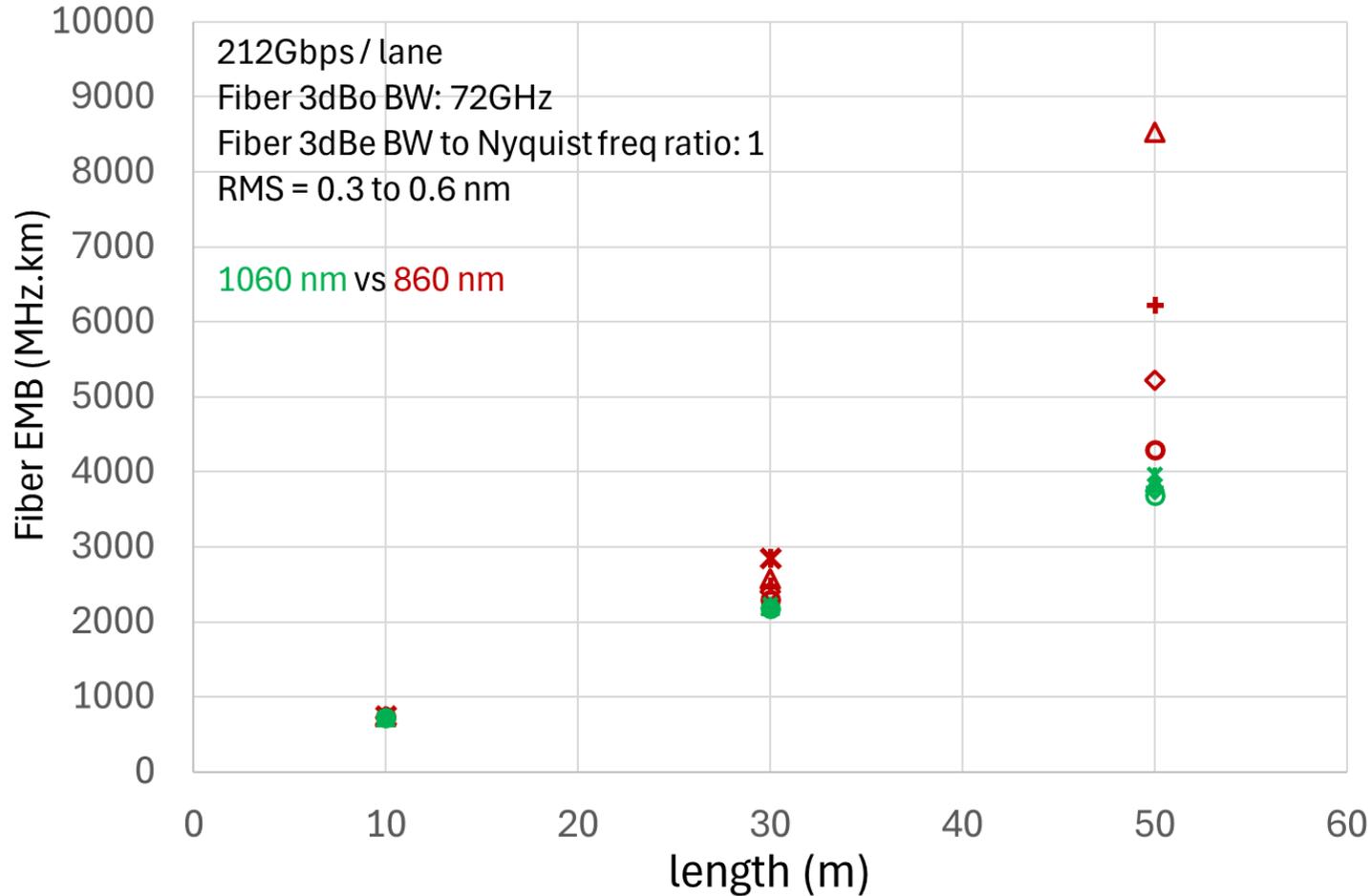
- longer reach

Nyquist freq. = 53.125 GHz

Notation on chart:

3dBo BW / 3dBe BW / Fiber 3dBe BW  
to Nyquist freq. ratio

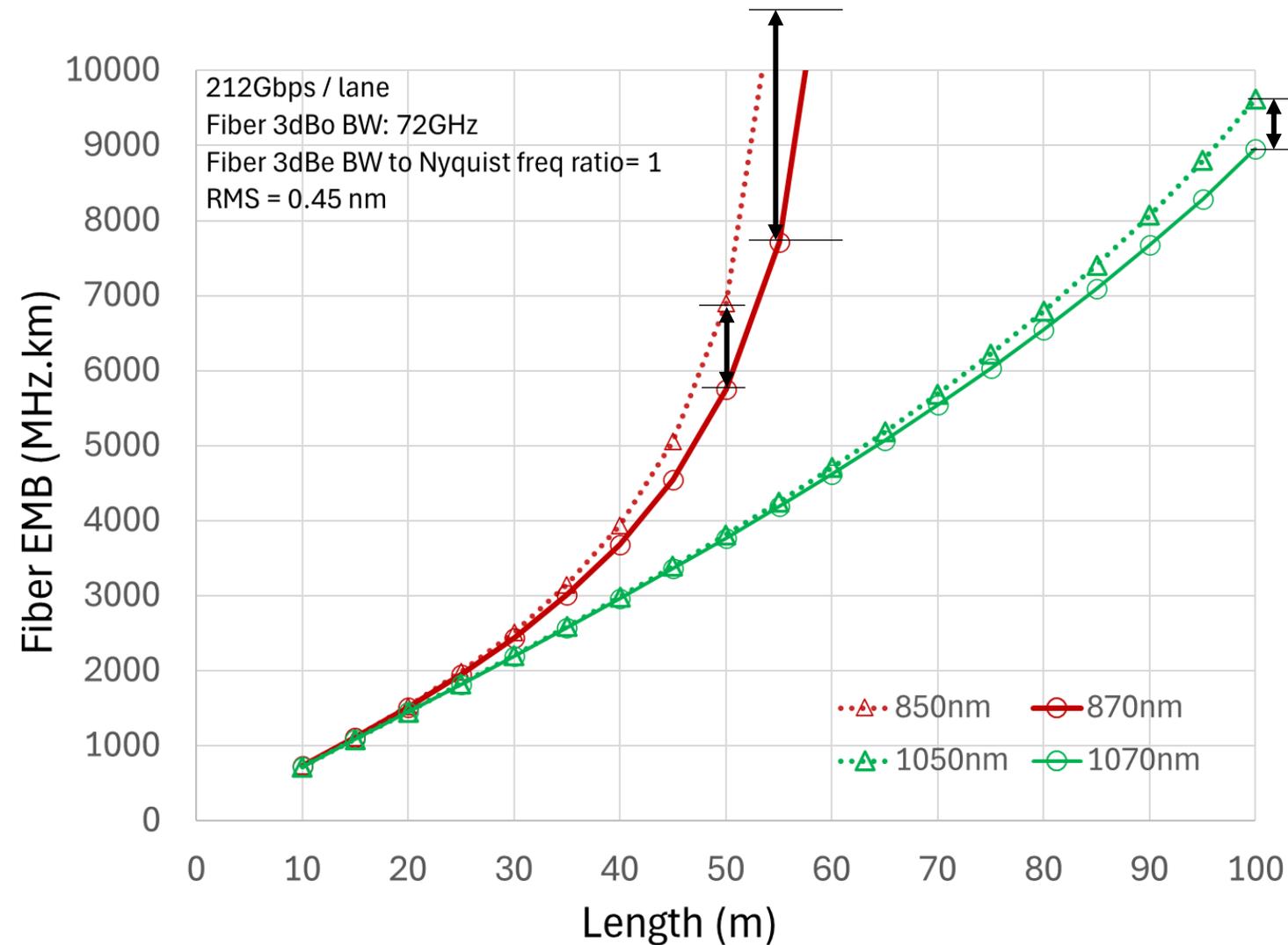
# Fiber EMB vs Reach @ 212Gbps/lane – RMS Sensitivity



At the same reach

- Fiber EMB is less sensitive to RMS variation at 1060 nm
- Advantage of 1060 nm is more obvious at longer reach

# Fiber EMB vs Reach @ 212Gbps/lane – Spectral Sensitivity

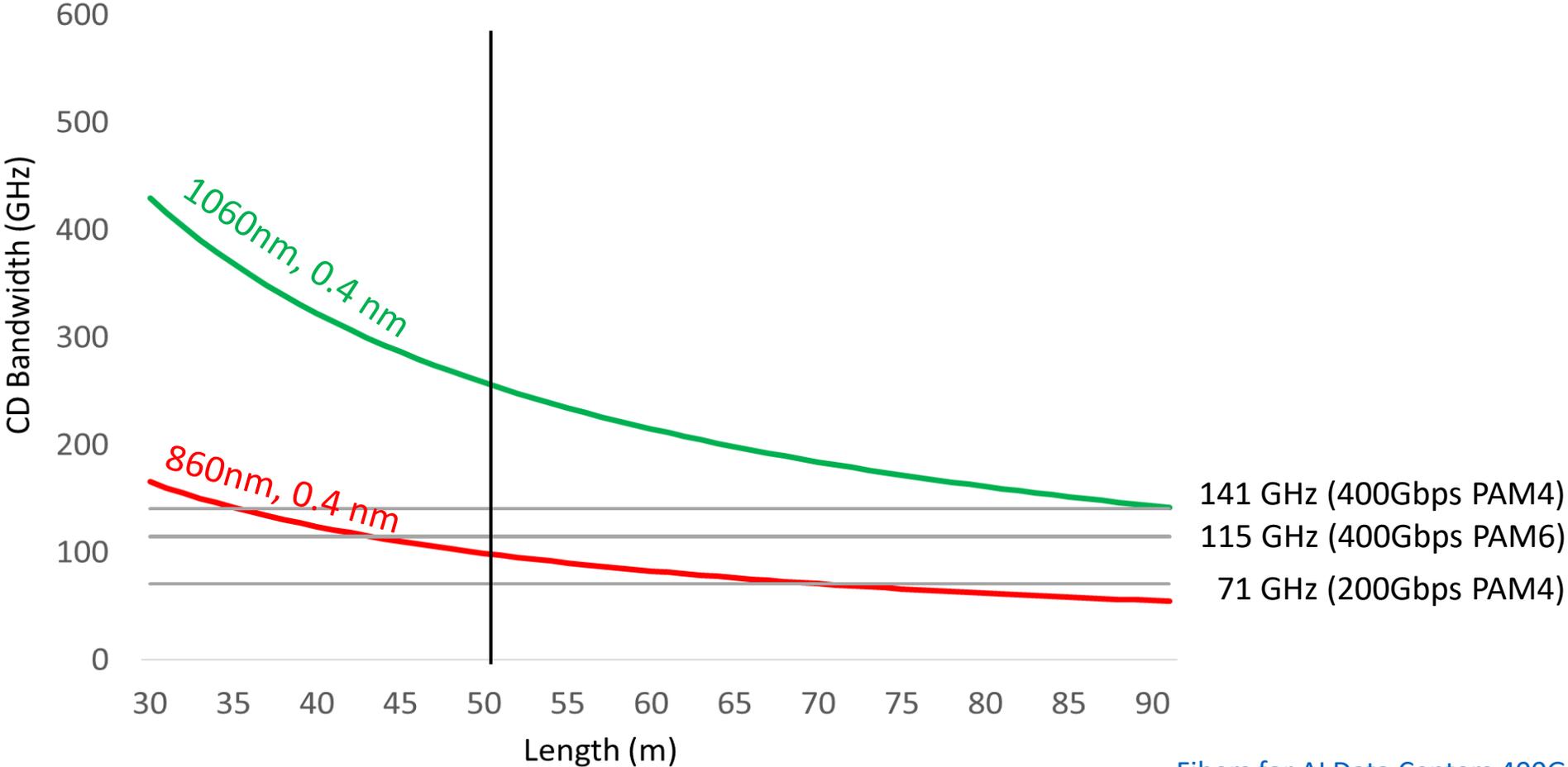


At the same reach

- Fiber EMB is less sensitive to spectral drift at 1060 nm band
- Advantage of 1060 nm band is more obvious at longer reach

# Moving to 400Gb/s/lane, longer reach enabled by 1060 nm

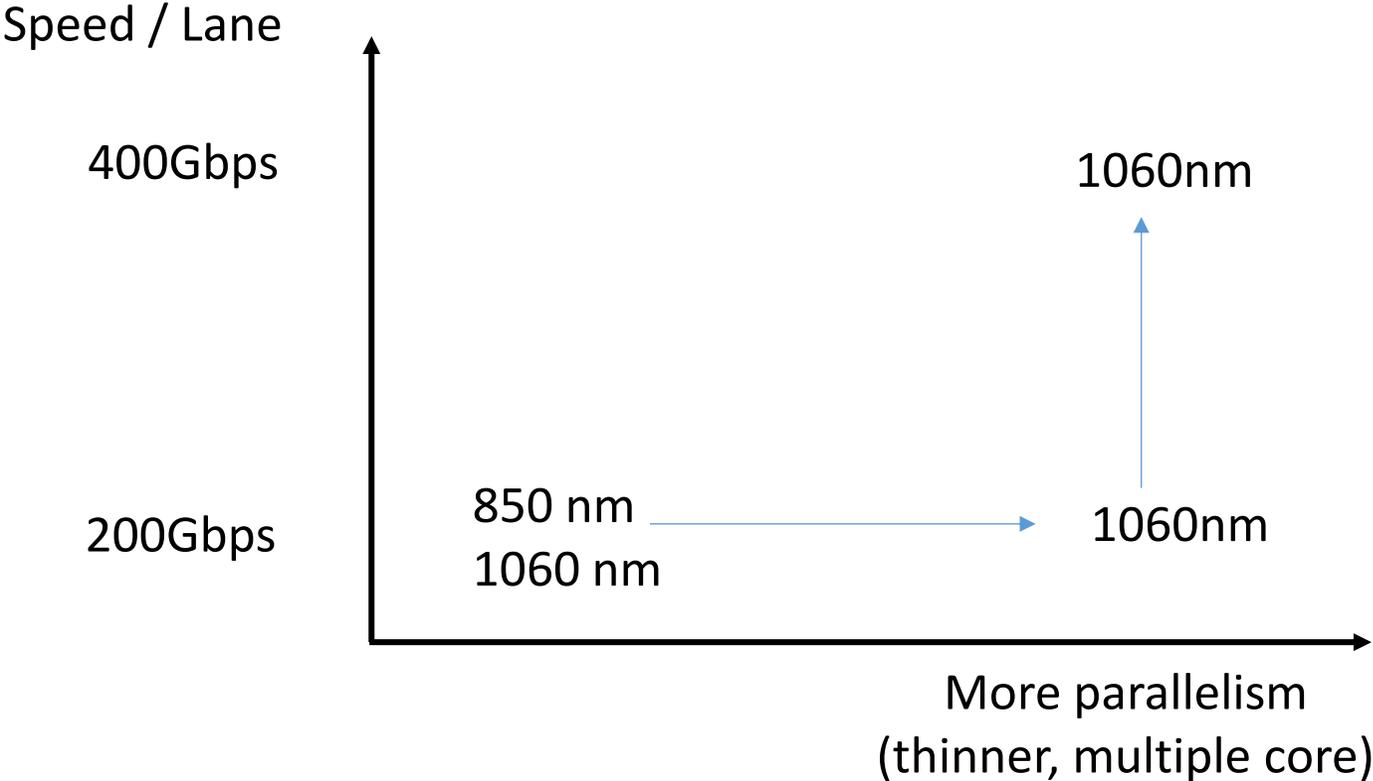
Reach extended by lower chromatic dispersion bandwidth



141 GHz (400Gbps PAM4)  
115 GHz (400Gbps PAM6)  
71 GHz (200Gbps PAM4)

[Fibers for AI Data Centers 400Gbps per Lane Applications,](#)  
Fiber for AI Workshop, Feb 24°, 2026

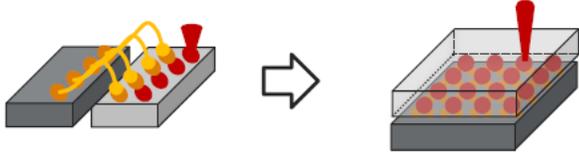
# Plausible Roadmap beyond IEEE 802.3ds 200Gbps/lane



- This contribution is focused on 200Gbps/lane signaling for IEEE P802.3ds MMF PMDs/PHYs, also indicating the potential future application for 1060 nm MMF, 1060 nm VCSEL-MMF links.

# 1060 VCSEL Benefits

**1060nm VCSEL technical benefits**



Metric	850nm	1060nm	Context
Fiber BW *	+	-	Working with fiber manufacturers on best path to 30m and 50m reach at 1060nm
Wall plug efficiency	+	+	Roughly equivalent efficiency, slightly lower voltage at 1060nm.
Emitter BW	-	+	Strained InGaAs active layer design enables 1.3x intrinsic BW, higher differential gain and efficiency
Signal Integrity	-	+	Flip chip integration removes group delay impedance issues known with wire-bonding..
Reliability	-	+	Flip chip and channel sparing takes FIT below 1. Al free active region enable high temp/high power reliability.
Detector technology	-	+	Flip chip detectors - higher speed / better responsivity than wire-bonded equivalent
Density	-	+	2D VCSEL arrays for high density interconnect including channel sparing
Thermal management	-	+	>20C lower laser junction, >20C lower ASIC temperature from flip chip driver/TIA assemblies
Manufacturability	-	+	Flip chip for mass reflow or TCB, also enables high accuracy placement for assembly
Volume	-	+	Builds on largest VCSEL deployments in history, reuses MFG partners, test, assembly supply chain

LUMENTUM IEEE 802.3 200 Gb/s per Wavelength MMF PHYs Study Group Meeting

Source:  
[muhigana\\_200gmmf\\_01b\\_2509.pdf](#) ,  
 "Proposal for 200Gbps 30m and 50m  
 MM Reach objectives using 1060nm",  
 IEEE 802.3 200 Gb/s per Wavelength  
 MMF PHYs Study Group Interim  
 Meeting, September 17, 2025

\* Fiber BW refers to the modal bandwidth at 1060 nm for a OM3/OM4/OM5 MMF, not for MMF optimized at 1060 nm.

# 1060 nm MMF Benefits (Fiber Expert Perspective)

Metric	860 nm high BW	1060 nm w. smaller core	Context
Standardization	+	-	Possibly more work within SDOs on 1060 nm due to core diameter and WL changes
Fiber development	+	-	Retuning BW to 1060 nm is trivial, geometry/core size change will require more work
Fiber testing	+	-	1060 nm sources are needed for testing
Fiber attenuation	-	+	Lower at 1060 nm (2.2 dB/km vs 0.9 dB/km)
Chromatic dispersion	-	+	2.6x lower at 1060 nm (98 ps/nm*km vs 38 ps/nm*km)
Modal BW required	-	+	Lower for 1060 fiber: we can possibly use “OM3 grade” for both 30m and 50m links
Lower grade fiber fallout	-	+	Can use OM3/4 grades of 1060 MMF, only OM4/4+ can be used for the 860 option
Coupling to PD	-	+	1060 is easier to couple to both top illuminated and lensed-substrate illuminated photodiodes which are already at < 20um diameter
Germanium use	-	+	Significantly lower Ge use for smaller core 1060 MMF (up to 75% less Ge)
Future upgrade path	-	+	1060 opens the path to >50 m reach, possibly future 400G applications
Density and SDM	-	+	Opens path to high-density small-clad MMF and MM MCF solutions
Fiber volume	-	+	Much higher volume/yield at 1060 nm due to lower EMB requirements and smaller core size
Fiber cost	-	+	Higher yields and lower Ge consumptions for 1060 nm potentially result in lower fiber cost relative to the cost of 860 nm

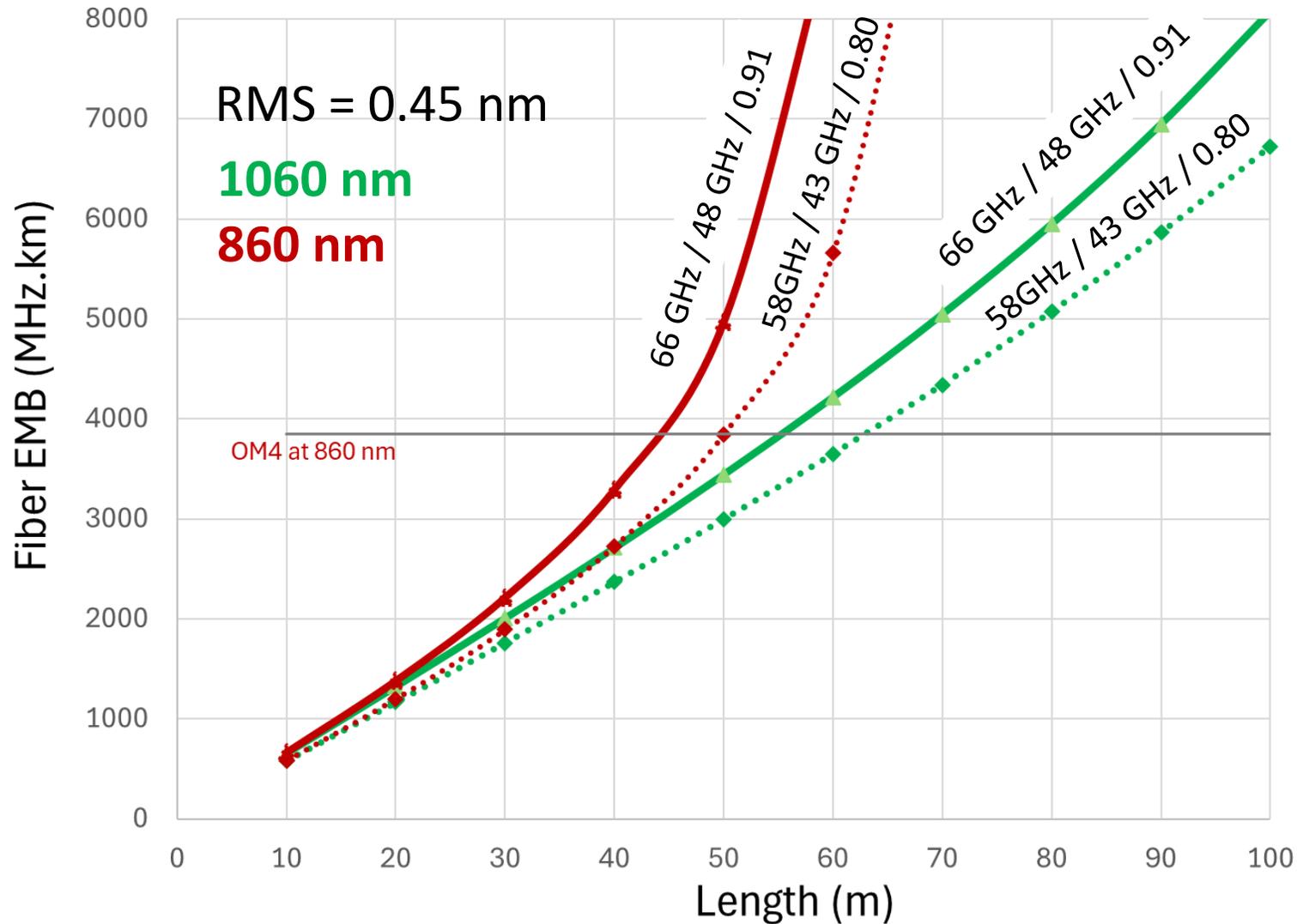
1060 nm VCSELs with a small-core 1060 nm MMF are potentially a higher yield, forward-looking high-reliability approach capable of meeting requirements for high volume AI scale-up applications.

We propose 802.3ds include a 1060 nm PMD and a 1060 nm optimized MMF.

We propose sending a liaison letter from IEEE to IEC requesting standardization of 1060 nm optimized MMFs.

# Back up

# Fiber EMB vs Reach @ 212Gbps/lane



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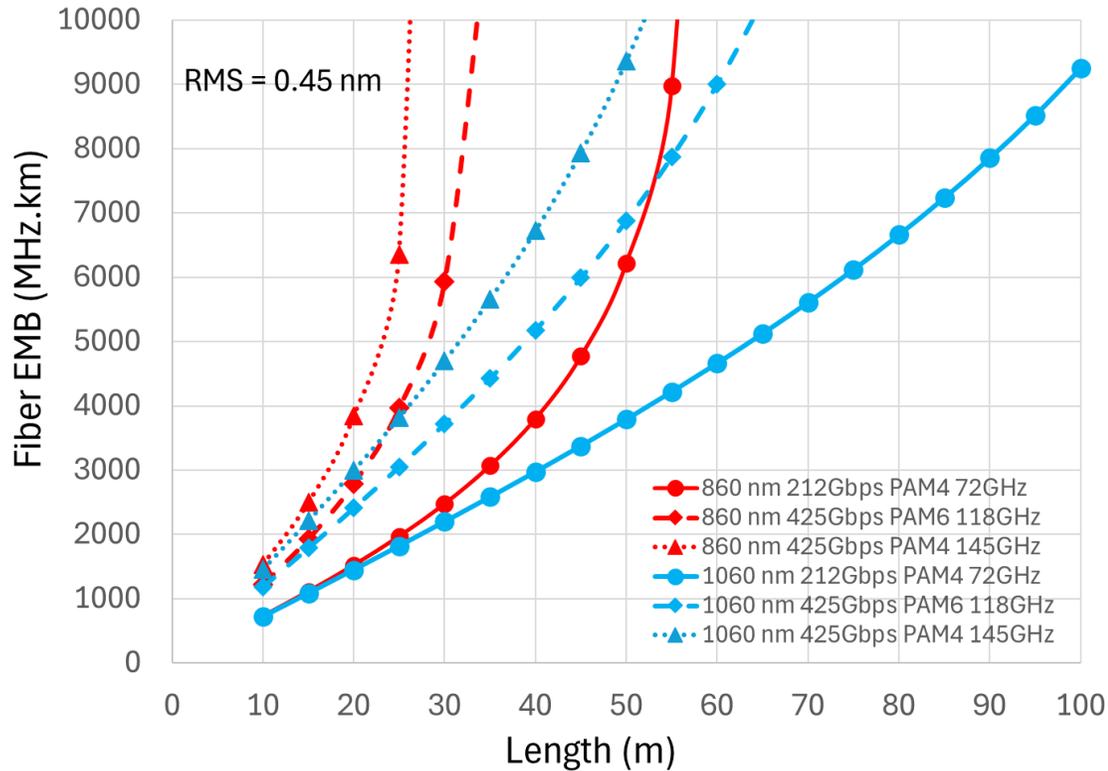
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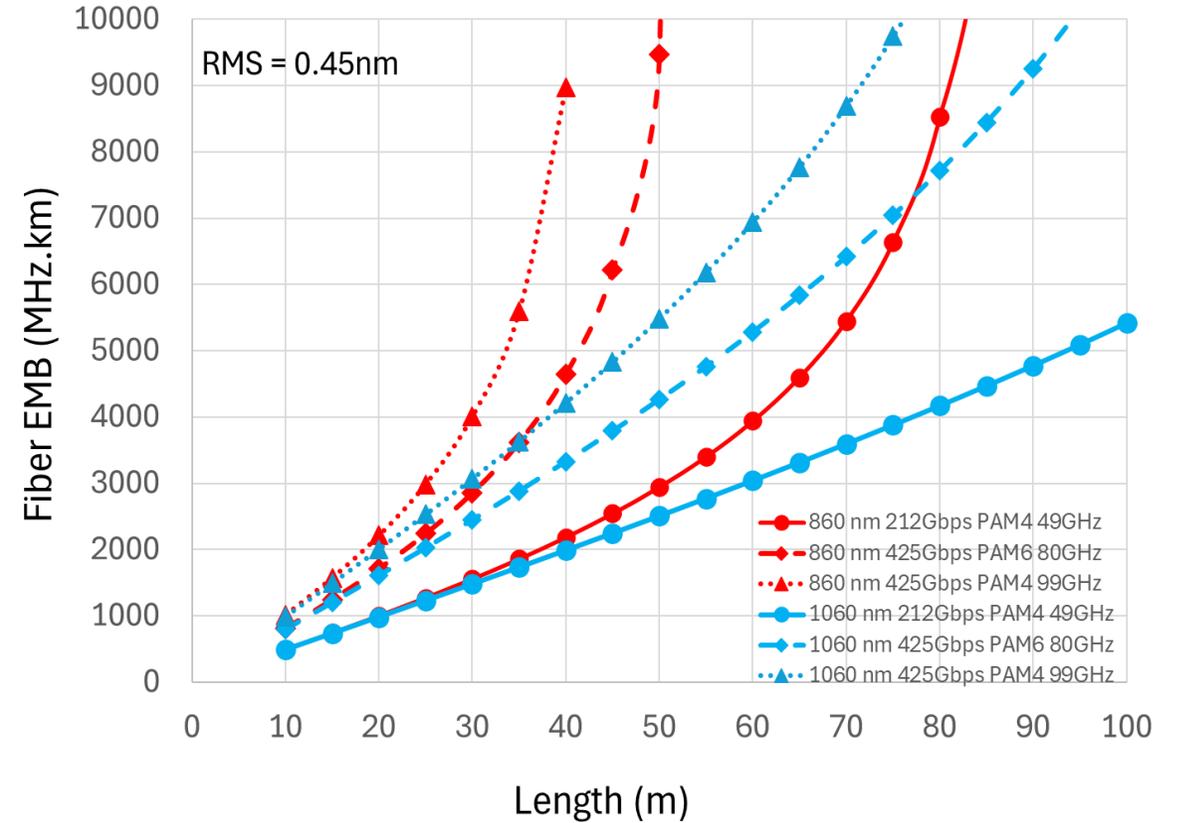
# What is possible at 400Gbps/lane?

More divergence on EMB needed between 850 nm and 1060 nm at

- Longer reach
- Higher speed
- Higher 3dB BW / Nyquist freq ratio



Fiber 3dBe BW / Nyquist Freq. = 1



Fiber 3dBe BW / Nyquist Freq. = 0.68